

# BRCS300C02MF

Rev.A Mar.-2024

## / Descriptions

SOT23-6

Complementary Enhancement MOSFET in a SOT23-6 Plastic Package.

## / Features

N-channel

$V_{DS}(V)=20V$

$I_D=5.0A$

$R_{DS(ON)}@4.5V<30m$  (TYP. 22mR)

$R_{DS(ON)}@2.5V<60$ (TYP. 30mR)

HF Product.

P-channel

$V_{DS}(V)=-20V$

$I_D=-2.8A$

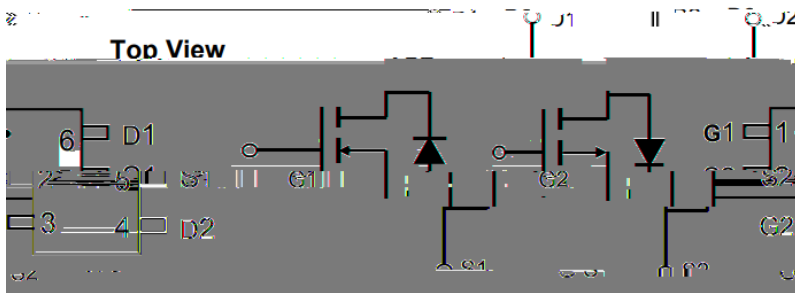
$R_{DS(ON)}@-4.5V<100m$  (TYP. 78mR)

$R_{DS(ON)}@-2.5V<150m$  (TYP. 107mR)

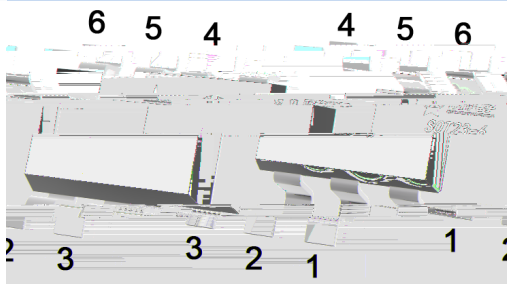
## / Applications

Power Management in Notebook computer, Portable Equipment and Battery powered systems.

## / Equivalent Circuit



## / Pinning



PIN1 G1 PIN 2 S2 PIN 3 G2

PIN 4 D2 PIN 5 S1 PIN 6 D1

## / Marking

See Marking Instructions.

# BRC300C02MF

Rev.A Mar.-2024

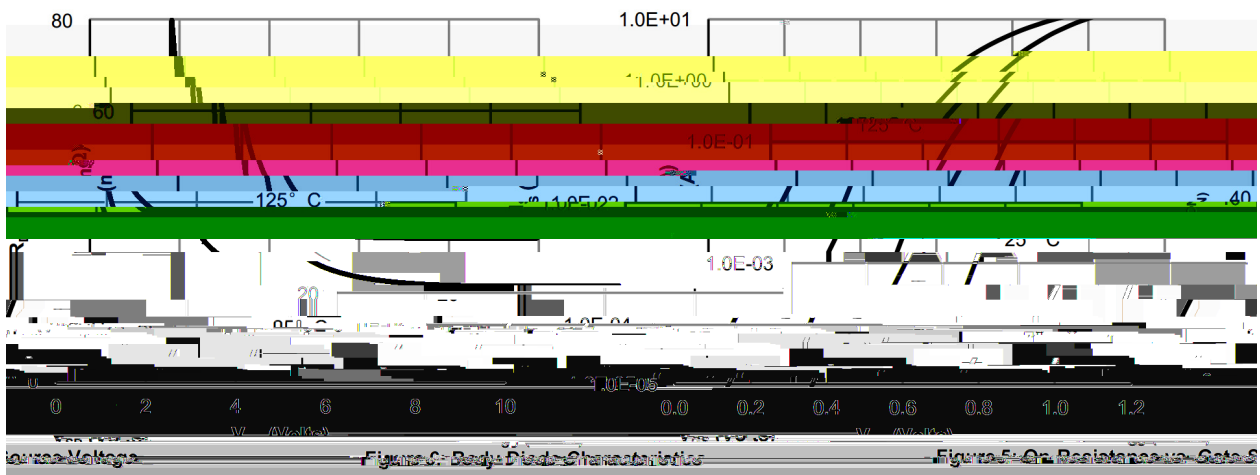
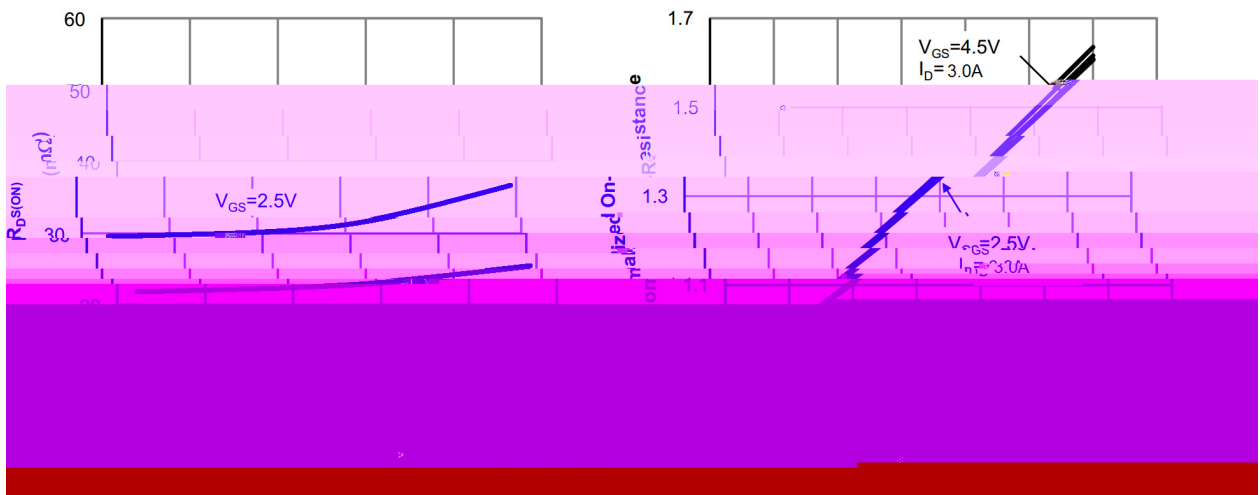
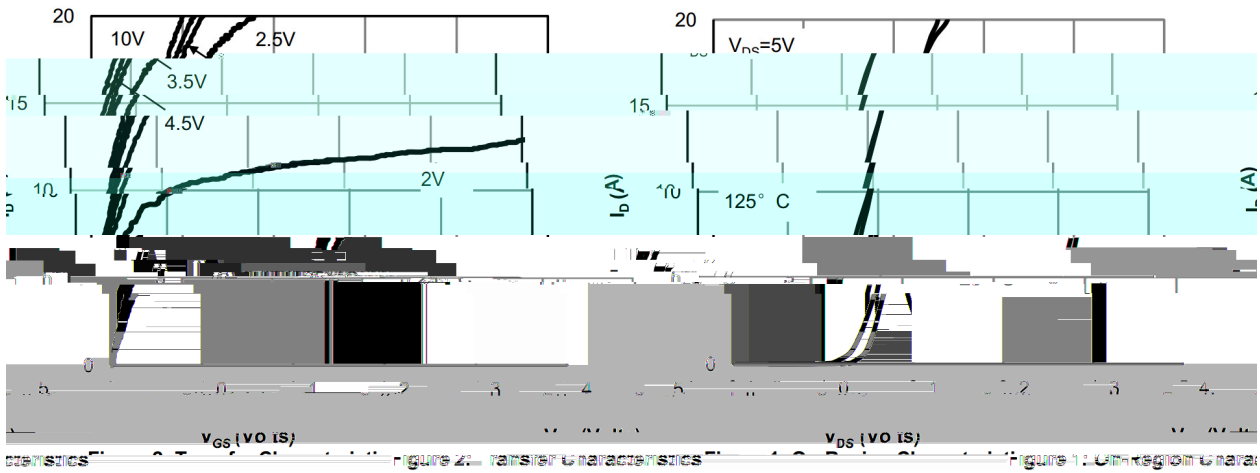


DATA SHEET

Parameter	Symbol	Rating		Unit
		N-channe	P-channell	
Drain-Source Voltage	$V_{DSS}$	20	-20	V
Gate-Source Voltage	$V_{GSS}$	±12		V
Continuous Drain Current	$I_D$	5.0	-2.8	A
Pulsed Drain Current	$I_{DM}$	20.4	-11.7	A
Power Dissipation	$P_D$	1.2	1.2	W
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150		
Maximum Junction-to-Ambient	$R_{JA}$	104		/W

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}$				

**N- / N-CHANNEL Electrical Characteristic Curve**



**N- / N-CHANNEL Electrical Characteristic Curve**

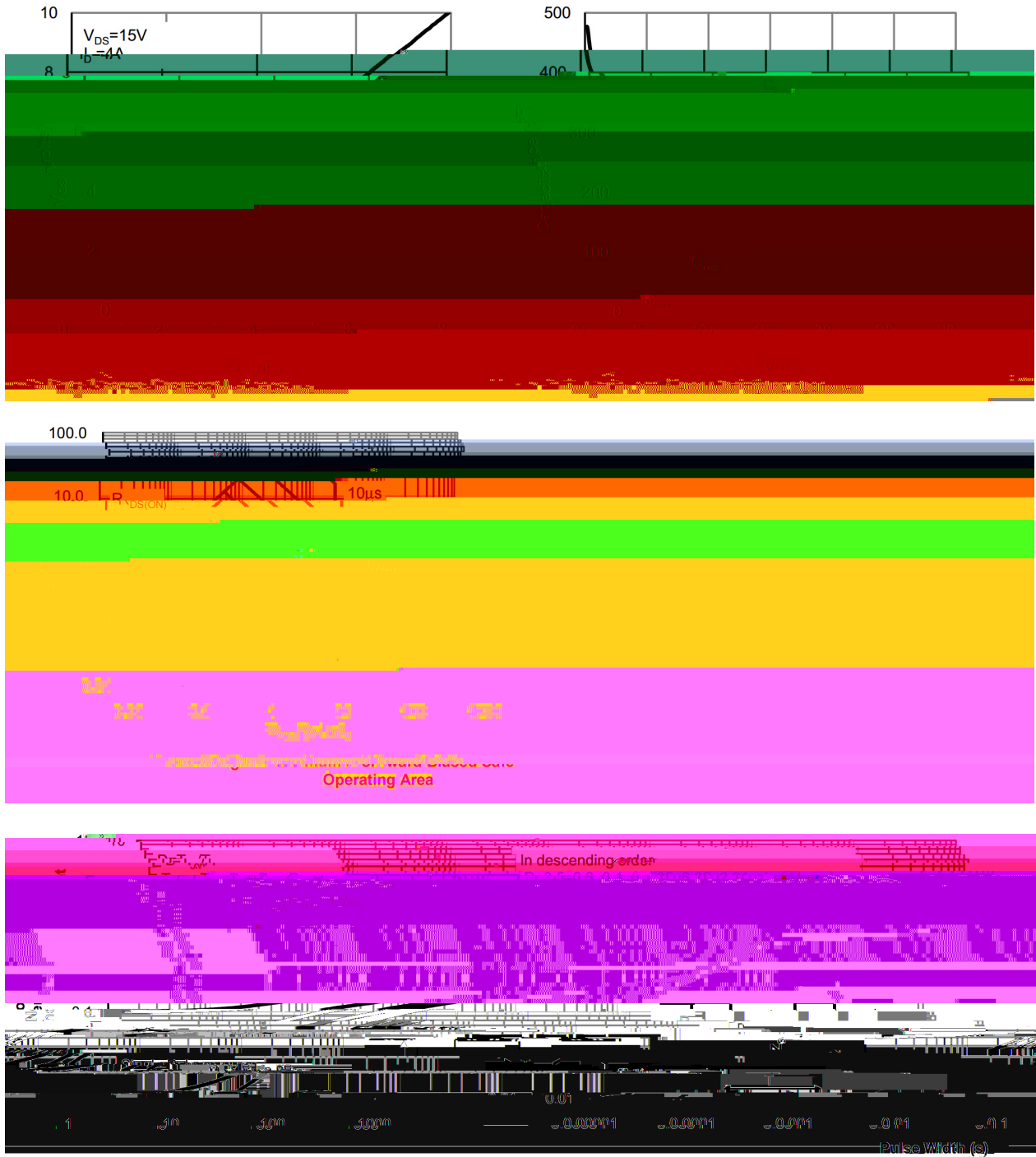


Figure 39: Normalized Maximum Transient Thermal Impedance

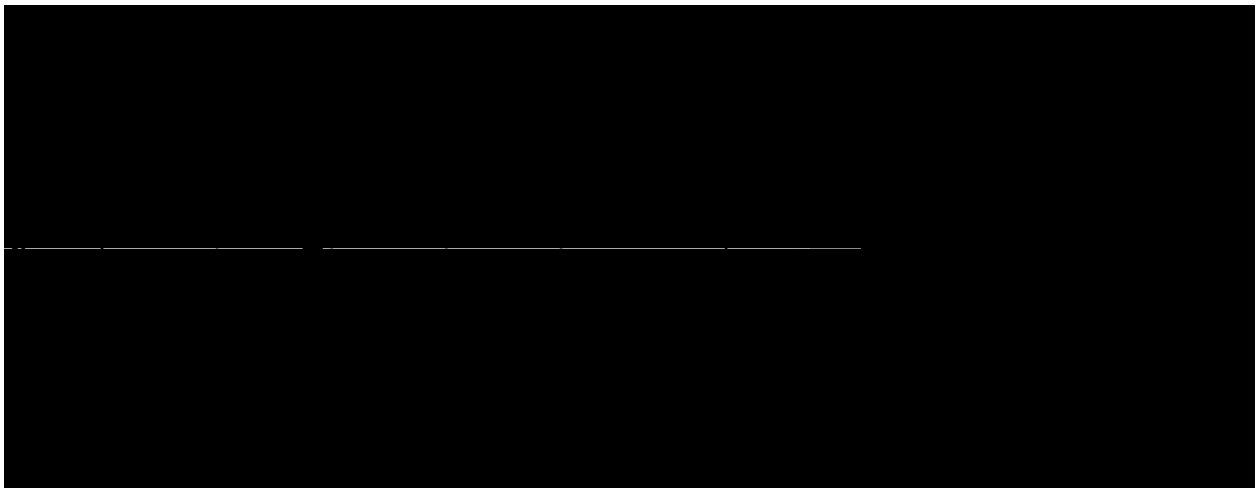
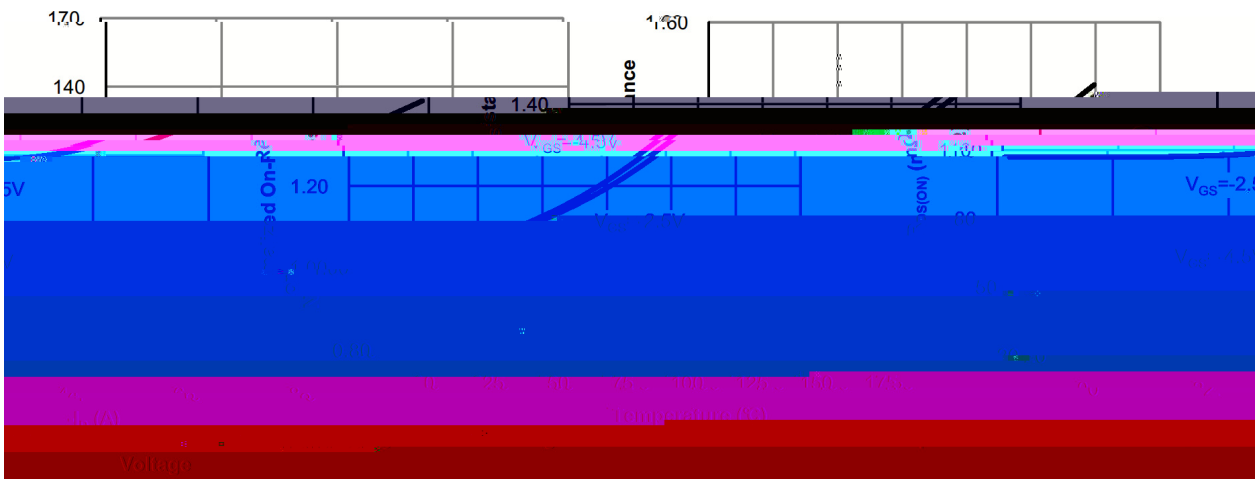
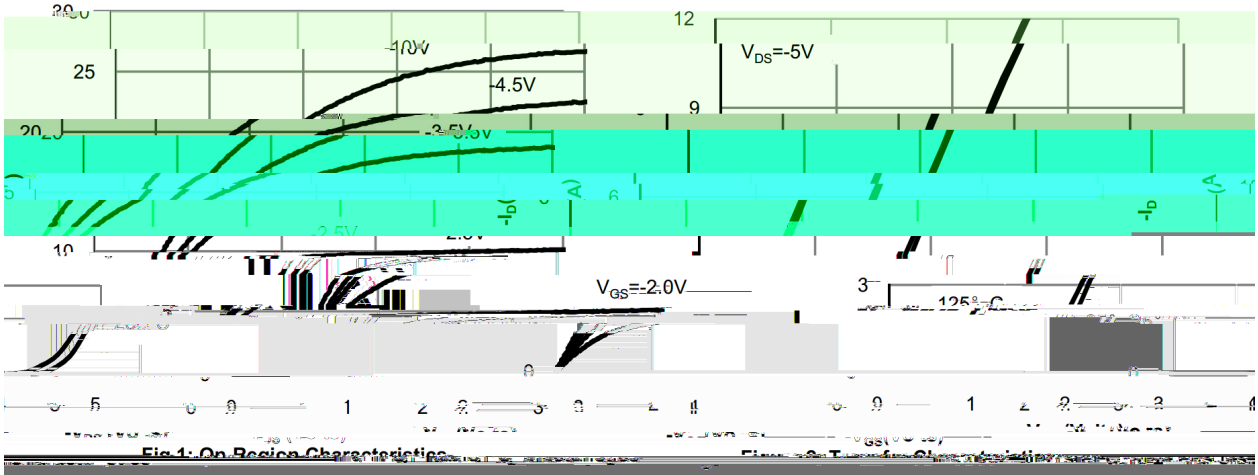
Figure 40: Normalized Maximum Transient Thermal Impedance

# **BRCS300C02MF**

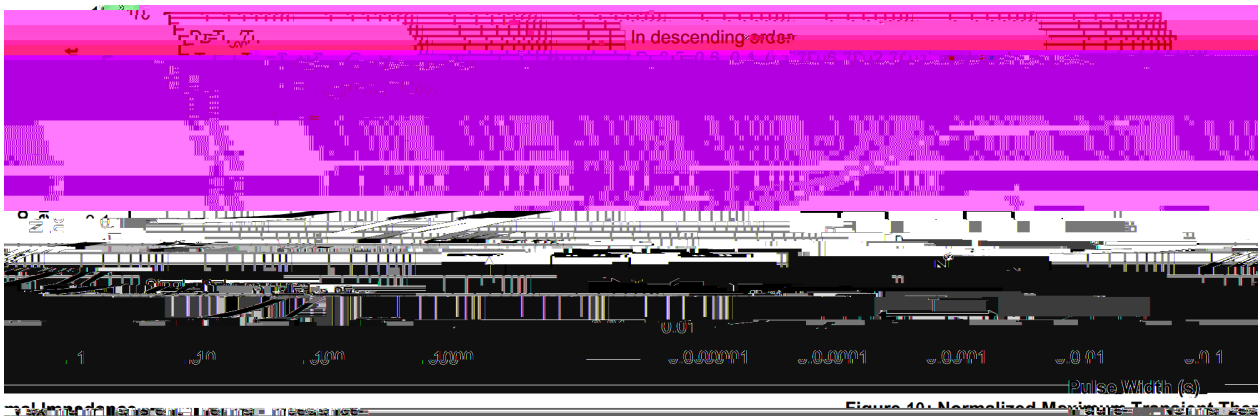
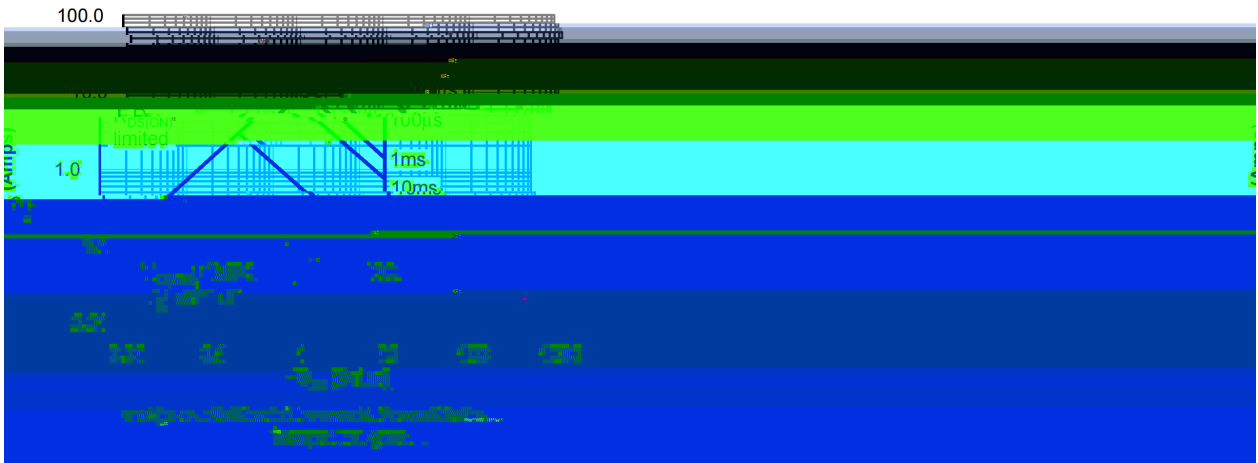
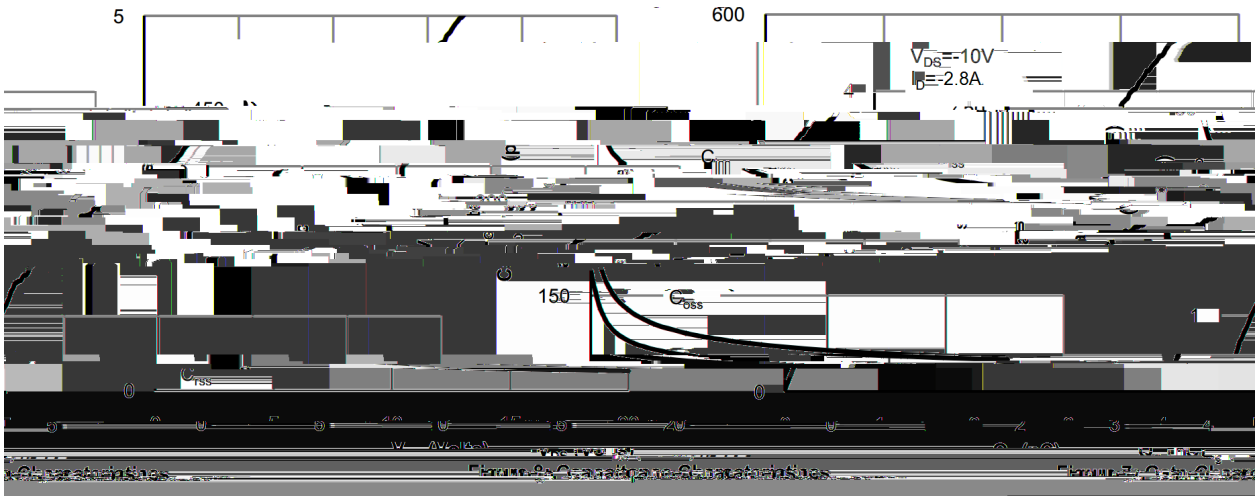
Rev.A Mar.-2024

**DATA SHEET**

**P- / P-CHANNEL Electrical Characteristic Curve**

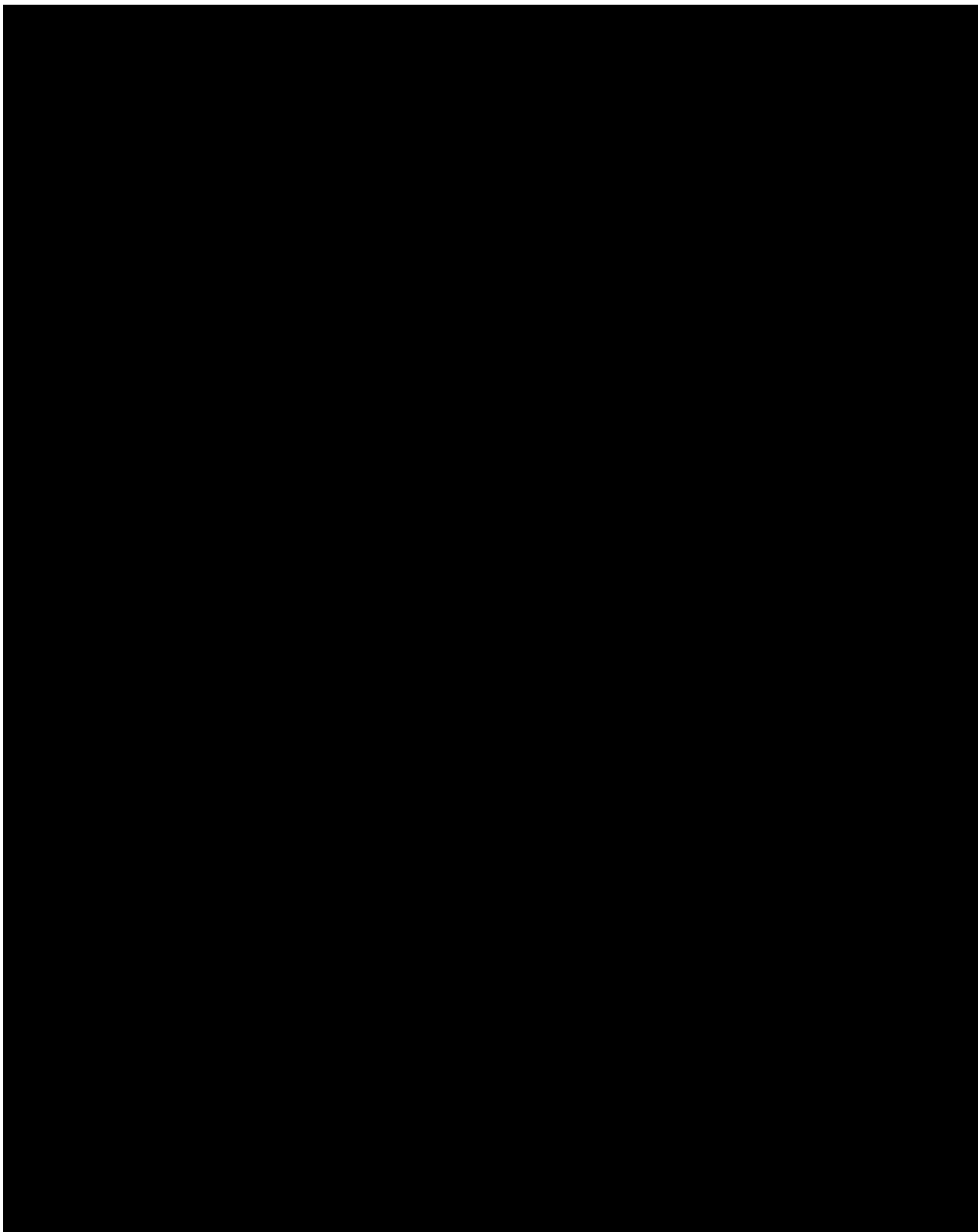


**P- / P-CHANNEL Electrical Characteristic Curve**





**/ Package Dimensions**



**BRCS300C02MF**

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)


Note:

1            150   180            60